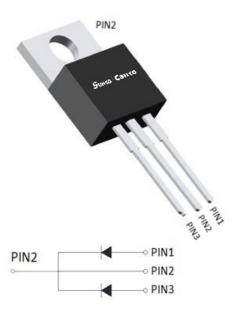


MBR1080CT THRU MBR10200CT

Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-220AB

Molding compound meets UL 94 V-0 flammability

rating,

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (T_a=25°C Unless otherwise specified)

- maximum rutumigo (rut = 0 = 0 minus = minus = sp = minus							
PARAMETER	SYMBOL	UNIT	MBR1080CT	MBR10100CT	MBR10120CT	MBR10150CT	MBR10200CT
Device marking code			MBR1080CT	MBR10100CT	MBR10120CT	MBR10150CT	MBR10200CT
Repetitive Peak Reverse Voltage	VRRM	V	80	100	120	150	200
Average Rectified Output Current @60Hz sine wave, R-load, T _a =25°C	Ю	Α	10				
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25℃	IFSM	Α	100				
Current Squared Time @1ms≤t≤8.3ms Tj=25°C	l ² t	A ² s	41				
Storage Temperature	T _{stg}	$^{\circ}$	-55 ~ +150				
Junction Temperature	Tj	$^{\circ}$	-55 ~ + 150				

■Electrical Characteristics (T_a=25 °C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR1080CT	MBR10100CT	MBR10120CT	MBR10150CT	MBR10200CT
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=5.0A	C).85	0	.9	0.95
Maximum DC reverse current	IRRM1	VRM=VRRM T _a =25℃				0.1		
at rated DC blocking voltage per diode	IRRM2	mA	VRM=VRRM T _a =100°C	20				

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS



MBR1080CT THRU MBR10200CT

■Thermal Characteristics (Ta=25 °C Unless otherwise specified)

PARA	METER	SYMBOL	UNIT	MBR1080CT	MBR10100CT	MBR10120CT	MBR10150CT	MBR10200CT
Thermal Resistance	Between junction and case	R _{θJ-C}	°CMV			2.0		

■Ordering Information (Example)

PREFERED P/N UNIT WEIGHT		UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
	MBR1080CT THRU MBR10200CT	Approximate 1.9	50	1000	5000	Tube

■Characteristics (Typical)

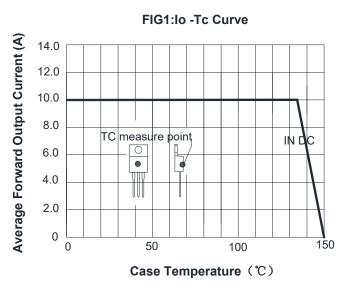
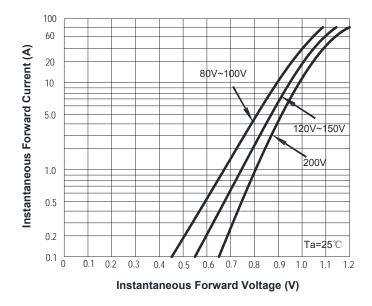


FIG2:Surge Forward Current Capability 140 Peak Forward Surge Current (A) 120 100 8.3ms Single Half Sine-Wave 80 JEDEC Method 60 40 20 2 10 20 50 100 **Number of Cycles**

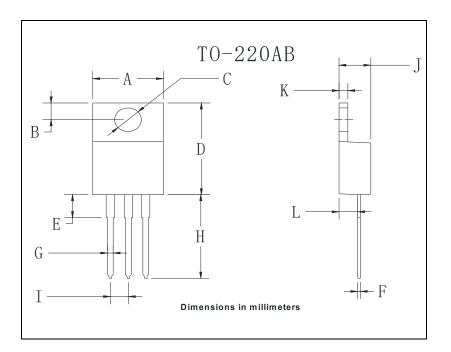
FIG3: Forward Voltage





MBR1080CT THRU MBR10200CT

■Outline Dimensions



TO-220AB						
Dim	Min	Max				
Α	9.95	10.35				
В	2.55	2.95				
С	3.8	4.0				
D	14.95	15.25				
Е	3.75	4.25				
F	0.26	0.5				
G	0.68	0.94				
Н	13.4	13.9				
I	2.35	2.65				
J	4.38	4.78				
K	1.14	1.4				
L	2.37	2.79				

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